

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

EMH1405 —

N-Channel Silicon MOSFET General-Purpose Switching Device Applications

Features

- ON-resistance $R_{DS}(on)1=14m\Omega(typ)$
- 4V drive
- Halogen free compliance
- $\cdot \,$ Protection diode in

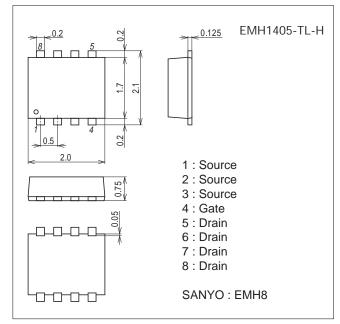
Specifications

Absolute Maximum Ratings at Ta=25°C

	-			
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱D		8.5	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	34	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (1200mm ² ×0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ.) 7045-001



Product & Package Information

- Package : EMH8
- JEITA, JEDEC
- Minimum Packing Quantity : 3,000 pcs./reel

: -

Taping Type : TL

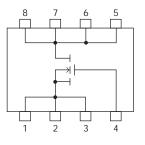
Marking

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Electrical Connection

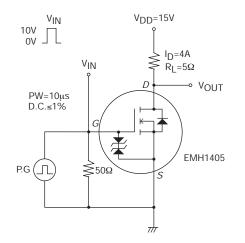


SANYO Semiconductor Co., Ltd. http://semicon.sanyo.com/en/network

Electrical	Characteristics at Ta=25°C	
Electrical	Characteristics at Ta=25°C	

Decemeter	Cumbal	Conditions	Ratings			
Parameter	Symbol	Conditions	min.	typ.	max.	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	VDS=10V, ID=4A		4.4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=4A, VGS=10V		14	19	mΩ
	R _{DS} (on)2	ID=2A, VGS=4.5V		24	34	mΩ
	R _{DS} (on)3	ID=2A, VGS=4V		30	42	mΩ
Input Capacitance	Ciss			820		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		130		pF
Reverse Transfer Capacitance	Crss			90		pF
Turn-ON Delay Time	t _d (on)			9.5		ns
Rise Time	tr		25			ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		63		ns
Fall Time	tf			28		ns
Total Gate Charge	Qg			15		nC
Gate-to-Source Charge	Qgs	V _{DS} =15V, V _{GS} =10V, I _D =8.5A		2.6		nC
Gate-to-Drain "Miller" Charge	Qgd	1		2.7		nC
Diode Forward Voltage	V _{SD}	IS=8.5A, VGS=0V		0.8	1.2	V

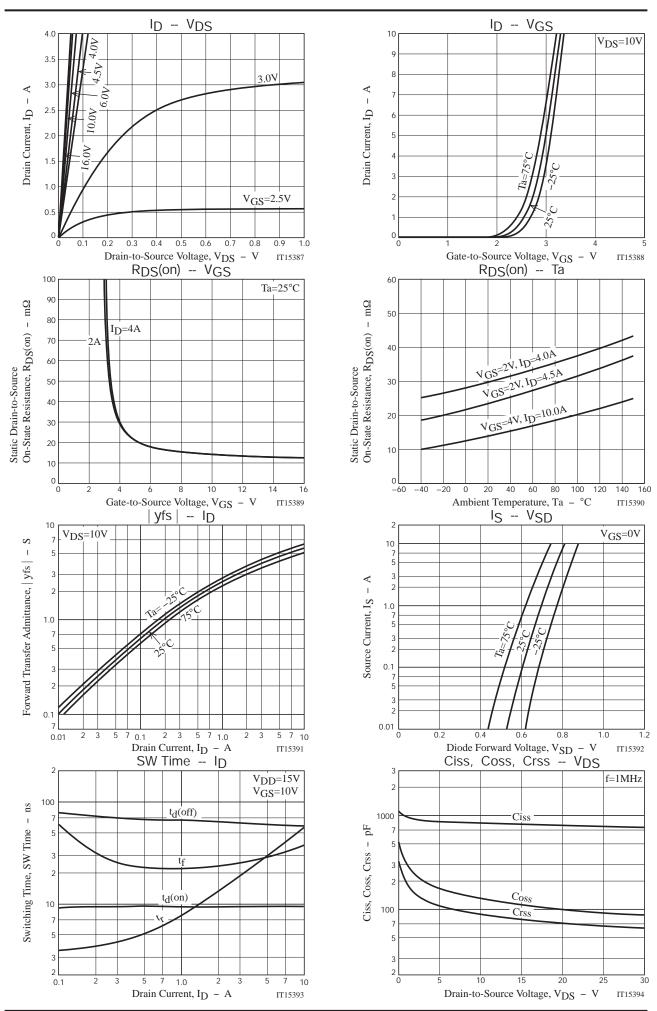
Switching Time Test Circuit

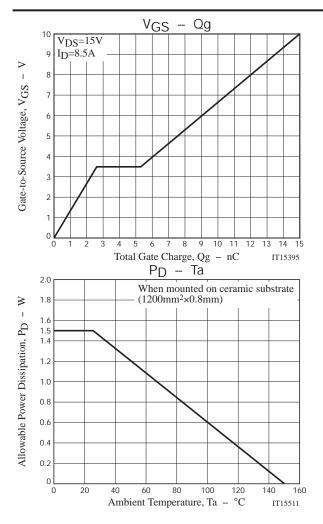


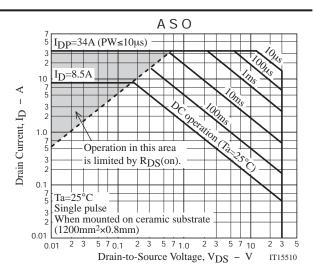
Ordering Information

Device	Package	Shipping	memo
EMH1405-TL-H	EMH8	3,000pcs./reel	Pb Free and Halogen Free

EMH1405







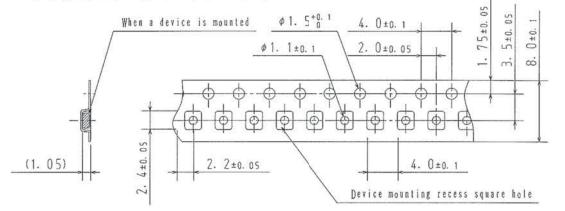
Embossed Taping Specification EMH1405-TL-H

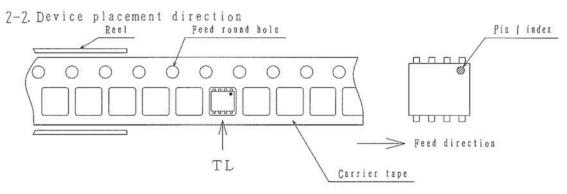
1. Packing Format

EMH8	Type MCP4	Reel	[nner box	Quter box	Innor	DAV		
EMH8	MCP4	2 000		Source 11, 245, 241	Innei	BOX	(C-1)	Outer BOX (A-7)
		3, 000	15, 000	90,000	5 reels co Dimension			6 inner boxes contained 1) Dimensions:mm (external)
					183×	72×	185	440×195×210
Packing meth	hod_		<u>Keei</u>	(u 1	nner <u>box</u> nit:mm) 59		It is The I	er box label a label at the time of factory shipmer orm of a label may change in physical ibution process. 108
	Type LOT I Quan	No.		17 LOT 00	UNITED IN THISTOPHIC NUTERING INTERTOOR O (1) LEAD FREE		80	TYPE CODE
	Orig	in	-> [_as	SSEMBLY:**** (DIFFUSION:****)			SPECIAL #20722005310C* ASSEMELY:***** (DIFFUSION:*****)
/	Reel la	bel	Th	e LEAD FR	REE ¥ descr of the term	iption inal	n shows is lead	that the surface free
				Label			Phase	
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2. Taping configuration

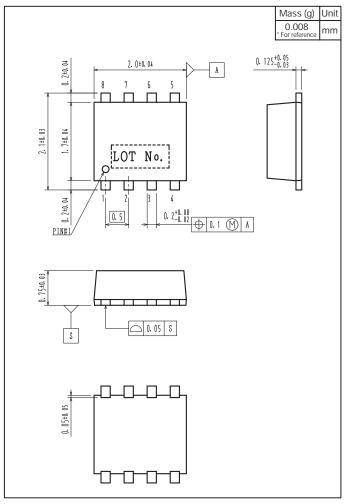
2-1. Carrier tape size (unit:mm)



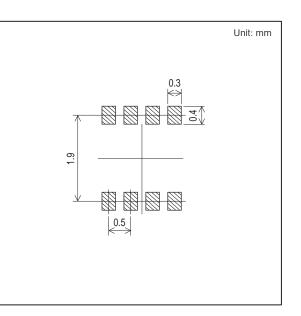


Those with pin 1 index on the feed hole side TL

Outline Drawing EMH1405-TL-H



Land Pattern Example



Note on usage : Since the EMH1405 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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